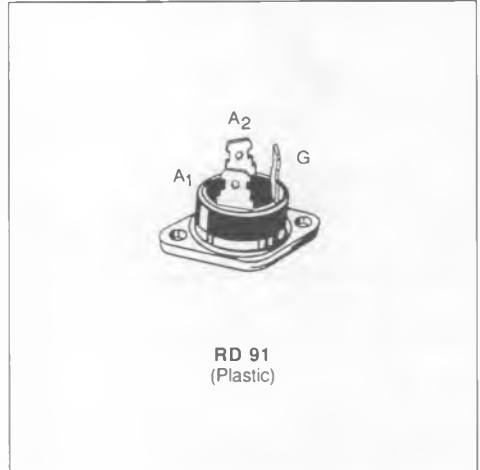


## ALTERNISTORS

- $(di/dt)_c < 142 \text{ A/ms}$  (400 Hz)
- INSULATING VOLTAGE : 2500  $V_{RMS}$   
( $t \leq 1 \text{ mn}$  -  $F = 50 \text{ Hz}$ )
- UL RECOGNIZED (EB1734)

### APPLICATIONS

- POWER CONTROL ON INDUCTIVE LOAD  
(motor, transformer...)
- HIGH FREQUENCY OR HIGH  $(di/dt)_c$  LEVEL CIRCUITS



### DESCRIPTION

New range of solid state AC - switches with very high commutating capability.

### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
$I_{T(RMS)}$	RMS on-state Current (360° conduction angle)	$T_C = 75 \text{ }^\circ\text{C}$	40	A
$I_{TSM}$	Non Repetitive Surge Peak on-state Current	$t = 10 \text{ ms}$	350	A
		$t = 8.3 \text{ ms}$	370	
		$t = 2.5 \text{ ms}$	590	
$I^2t$	$I^2t$ Value for Fusing	$t = 10 \text{ ms}$	610	$\text{A}^2\text{s}$
$di/dt$	Critical Rate of Rise of on-state Current (1)		100	$\text{A}/\mu\text{s}$
$T_{stg}$ $T_j$	Storage and Operating Junction Temperature Range		- 40 to 125 - 40 to 125	$^\circ\text{C}$ $^\circ\text{C}$

Symbol	Parameter	TODV							Unit
		140	240	440	640	840	1040	1240	
$V_{DRM}$	Repetitive Peak off-state Voltage (2)	100	200	400	600	800	1000	1200	V

(1)  $I_G = 1.5 \text{ A}$   $di_c/dt = 1 \text{ A}/\mu\text{s}$

(2)  $T_j = 125 \text{ }^\circ\text{C}$ .

### THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(c-h)}$	Contact (case-heatsink) with Grease	0.1	$^\circ\text{C}/\text{W}$
$R_{th(j-c)} \text{ DC}$	Junction to Case for DC	1.2	$^\circ\text{C}/\text{W}$
$R_{th(j-c)} \text{ AC}$	Junction to Case for 360° Conduction Angle ( $F = 50 \text{ Hz}$ )	0.9	$^\circ\text{C}/\text{W}$

**GATE CHARACTERISTICS** (maximum values)

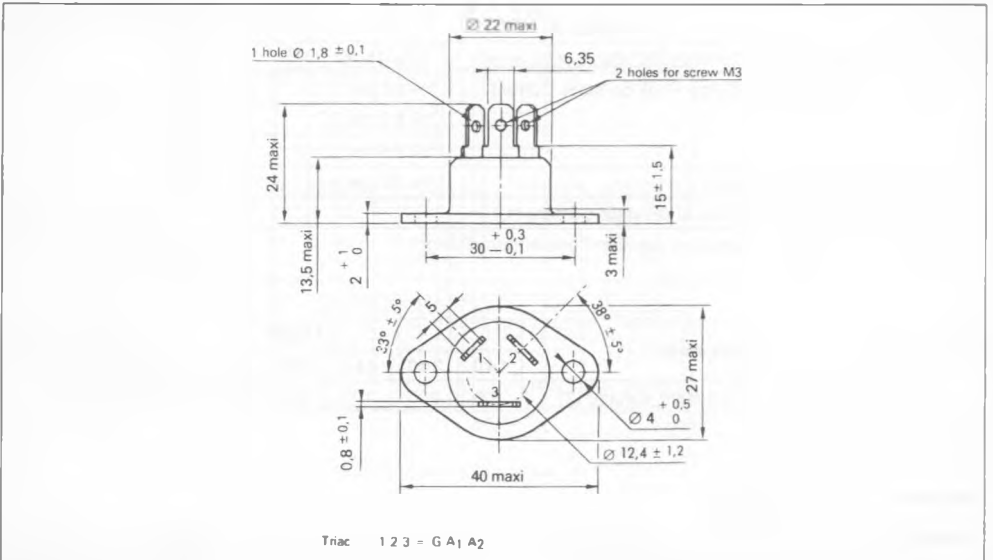
$P_{GM} = 40 \text{ W}$  ( $t_p = 10 \mu\text{s}$ )       $I_{GM} = 8 \text{ A}$  ( $t_p = 10 \mu\text{s}$ )  
 $P_{G(AV)} = 1 \text{ W}$        $V_{GM} = 16 \text{ V}$  ( $t_p = 10 \mu\text{s}$ )

**ELECTRICAL CHARACTERISTICS**

Symbol	Test Conditions	Quadrants	Min.	Typ.	Max.	Unit
$I_{GT}$	$T_j = 25 \text{ }^\circ\text{C}$ $V_D = 12 \text{ V}$ $R_L = 33 \text{ } \Omega$ Pulse Duration > 20 $\mu\text{s}$	I-II-III			200	mA
$V_{GT}$	$T_j = 25 \text{ }^\circ\text{C}$ $V_D = 12 \text{ V}$ $R_L = 33 \text{ } \Omega$ Pulse Duration > 20 $\mu\text{s}$	I-II-III			1.5	V
$V_{GD}$	$T_j = 125 \text{ }^\circ\text{C}$ $V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$	I-II-III	0.2			V
$I_H^*$	$T_j = 25 \text{ }^\circ\text{C}$ $I_T = 500 \text{ mA}$ Gate Open			50		mA
$I_L$	$T_j = 25 \text{ }^\circ\text{C}$ $V_D = 12 \text{ V}$ $I_G = 400 \text{ mA}$ Pulse Duration > 20 $\mu\text{s}$	I-III		50		mA
		II		100		
$V_{TM}^*$	$T_j = 25 \text{ }^\circ\text{C}$ $I_{TM} = 60 \text{ A}$ $t_p = 10 \text{ ms}$				1.8	V
$I_{DRM}^*$	$T_j = 125 \text{ }^\circ\text{C}$ $V_{DRM}$ Specified				8	mA
$dv/dt^*$	$T_j = 125 \text{ }^\circ\text{C}$ Gate Open Linear Slope up to $V_D = 67\% V_{DRM}$	$V_{DRM} \leq 800 \text{ V}$		500		$V/\mu\text{s}$
		$V_{DRM} \geq 1000 \text{ V}$		250		
$(di/dt)_c^*$	$T_C = 75 \text{ }^\circ\text{C}$ $V_D = V_{DRM}$ $I_T = 60 \text{ A}$	$(dv/dt)_c = 200 \text{ V}/\mu\text{s}$		35		A/ms
		$(dv/dt)_c = 10 \text{ V}/\mu\text{s}$		142		
$t_{gt}$	$T_j = 25 \text{ }^\circ\text{C}$ $V_D = V_{DRM}$ $I_T = 60 \text{ A}$ $I_G = 0.5 \text{ A}$ $di_G/dt = 3.5 \text{ A}/\mu\text{s}$	I-II-III		2.5		$\mu\text{s}$

\* For either polarity of electrode  $A_2$  voltage with reference to electrode  $A_1$ .

**PACKAGE MECHANICAL DATA : RD 91 Plastic**



Cooling method : by conduction (method C)  
 Marking : type number  
 Weight : 15 g

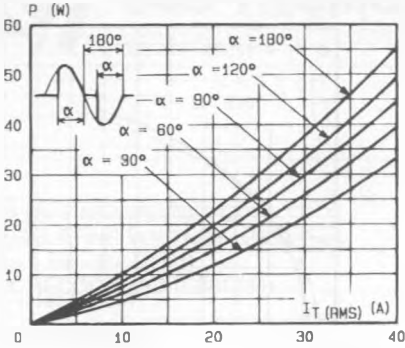


Fig.1 - Maximum mean power dissipation versus RMS on-state current.

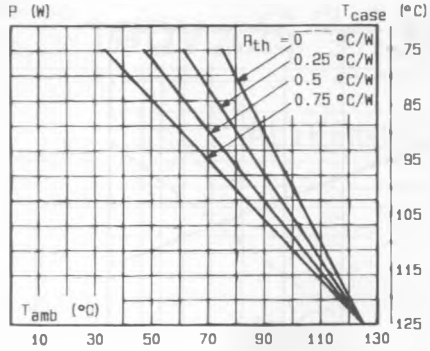


Fig.2 - Correlation between maximum mean power dissipation and maximum allowable temperatures ( $T_{amb}$  and  $T_{case}$ ) for different thermal resistances heatsink + contact.

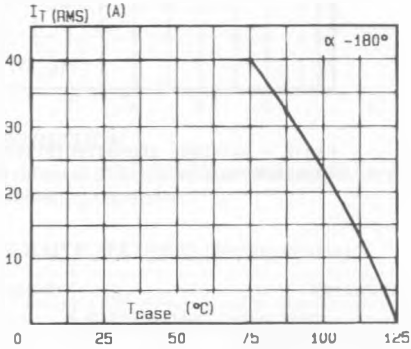


Fig.3 - RMS on-state current versus case temperature.

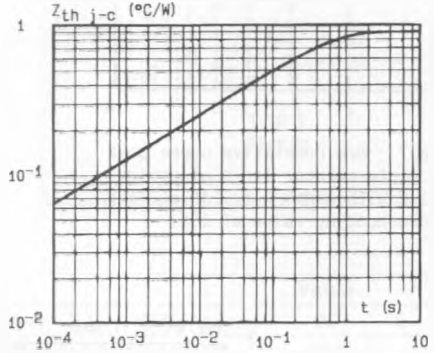


Fig.4 - Thermal transient impedance junction to case versus pulse duration.

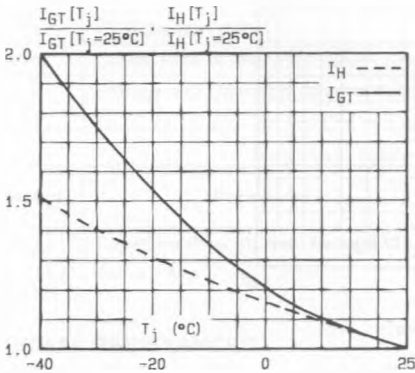


Fig.5 - Relative variation of gate trigger current and holding current versus junction temperature.

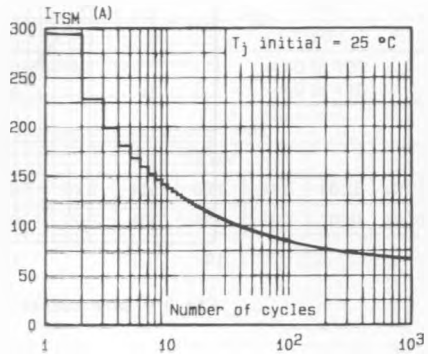


Fig.6 - Non repetitive surge peak on-state current versus number of cycles.

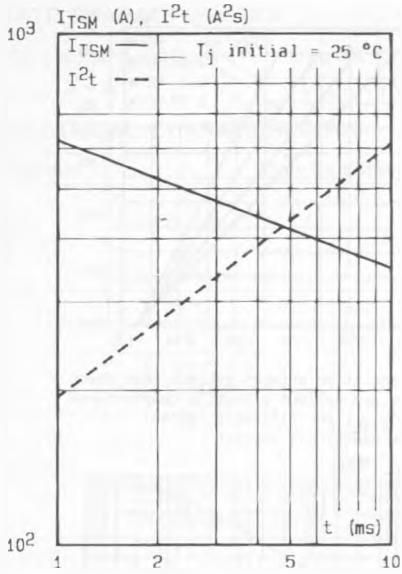


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width :  $t \leq 10$  ms, and corresponding value of  $I^2t$ .

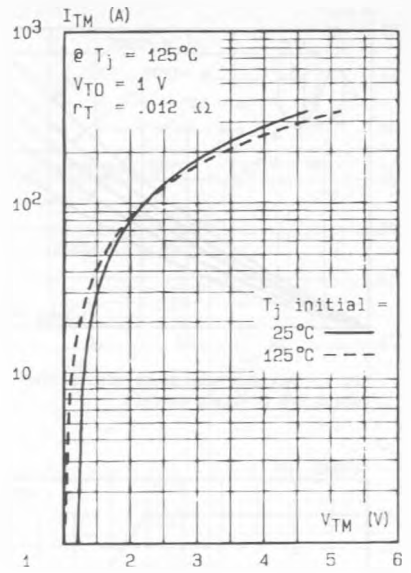


Fig.8 - On-state characteristics (maximum values).

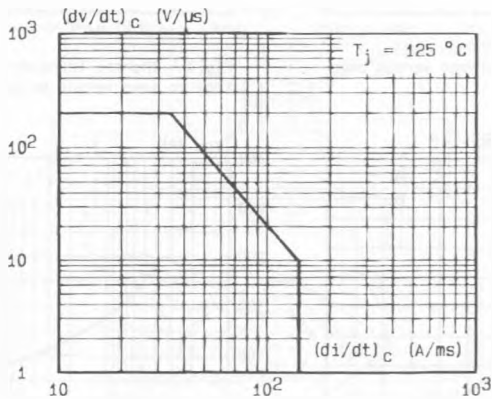


Fig.9 - Safe operating area.